	Туре	L#	Hits	Search Text	DBs	Time Stamp	en	Er ro r De fi ni ti	Er ro rs
1	IS&R	L1	2	("6858480").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:28			
2	BRS	L3	48	catalyst and	HISDAT. EDO.	2005/11/26 23:10			
3	BRS	L4	15	or alpha) with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:39			

	Type	L#	Hits	Search Text	DBs	Time Stamp	L i	Er ro rs
4	BRS	L5		or alpha) with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:39		
5	BRS	L6	2	or alpha) with crystal\$9 with catalyst and second with (getter\$4 or remov\$4) with catalyst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:39		
6	BRS	L7	11	· •	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:39		

	Туре	L #	Hits	Search Text	DBs	Time Stamp	I	Er ro rs
7	BRS	L8	0	or alpha) with crystal\$9 with catalyst and second with (getter\$4 or remov\$4) with catalyst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:40		
8	BRS	L10	i	or alpha) with crystal\$9 with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:40		
9	BRS	L9	4	or alpha) with crystal\$9 with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:46		

	Туре	L #	Hits	Search Text	DBs	Time Stamp		Er ro rs
10	BRS	L11	l .	or alpha) with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:54		
11	BRS	L12	1	catalyst and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 20:57		

	Туре	L#	Hits	Search Text	DBs	Time Stamp	1	l 1	Er ro rs
12	BRS	L13	11	catalyst and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 21:16			
13	BRS	L14	1	("438"/\$).ccls. and semiconductor and (amorphous or alpha) with crystal\$9 with catalyst and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 21:16			
14	BRS	L16	16	115 not 111	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 21:17			

	Туре	L #	Hits	Search Text	DBs	Time Stamp	en	Er ro r De fi ni ti	Er ro rs
15	BRS	L17	6	115 not 114	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 21:18			
16	BRS	L15	17	(second or	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 23:10			
17	BRS	L18	7	(semiconductor and (amorphous or alpha) with crystal\$9 with catalyst and (second or multiple or	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/26 23:11			